L Number	Hits	Search Text	DB	Time stamp
-	19	(("6,255,166") or ("5,408,115") or ("5,969,383") or ("5,422,504") or ("5,494,838") or ("6,177,318") or ("6,248,633") or ("2002-0100929") or ("2002-0127805") or ("6,413,821") or ("6,518,124") or ("2003-0054610") or ("2003-0057505") or ("2003-0058705") or ("2003-0060011") or ("2003-0190805") or ("2003-0186505") or ("2003-0166321") or ("2003-0157767") or ("2003-0166322") or ("2003-0166320") or ("2003-0211691")).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 11:08
-	24	(("20020100929") or ("20020127805") or ("20030054610") or ("20030057505") or ("20030058705") or ("20030060011") or ("20030190805") or ("20030186505") or ("20030166321") or ("20030157767") or ("20030166322") or ("20030166320") or ("2003-0211691")).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/11 11:11
-	288765	(metal adj oxide adj nitride adj oxide adj semiconductor) or MONOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/12 08:58
-	291074	(metal adj oxide adj nitride adj oxide adj semiconductor) or MONOS or (silicon adj oxide adj nitride adj oxide adj silicon) or SONOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/12 09:01
-	759	((metal adj oxide adj nitride adj oxide adj semiconductor) or MONOS or (silicon adj oxide adj nitride adj oxide adj silicon) or SONOS) and (control adj gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/12 09:02
-	33	((metal adj oxide adj nitride adj oxide adj semiconductor) or MONOS or (silicon adj oxide adj nitride adj oxide adj silicon) or SONOS) and ((control adj gate) with (word adj gate) with ONO)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/12 09:03